

PART OBSOLETE - USE MMDT3946-7-F



MMDT4146

COMPLEMENTARY NPN / PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Complementary Pair One 4124-Type NPN One 4126-Type PNP
- **Epitaxial Planar Die Construction**
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.006 grams (approximate)





E1, B1, C1 = PNP4126 Section E2, B2, C2 = NPN4124 Section

Device Schematic

Maximum Ratings, NPN 4124 Section @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Collector Current – Continuous (Note 1)	lc	200	mA

Maximum Ratings, PNP 4126 Section @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-25	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-25	V
Emitter-Base Voltage	V_{EBO}	-4	V
Collector Current - Continuous (Note 1)	lc	-200	mA

Thermal Characteristics – Total Device

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 1, 2)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{\rm eJA}$	625	°C/W

Notes:

- Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- Maximum combined dissipation.
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics, NPN 4124 Section @TA = 25°C unless otherwise specified

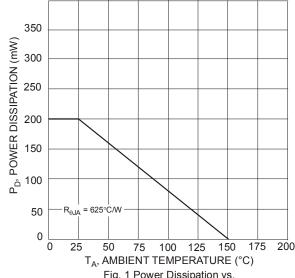
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)				•	
Collector-Base Breakdown Voltage	V _{(BR)CBO}	30	_	V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	25	_	V	I _C = 1.0mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5.0	_	V	$I_E = 10 \mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}		50	nA	$V_{CB} = 20V, I_{E} = 0V$
Emitter Cutoff Current	I _{EBO}	_	50	nA	V _{EB} = 3.0V, I _C = 0V
ON CHARACTERISTICS (Note 6)					
DC Current Gain	h	120	360		I _C = 2.0mA, V _{CE} = 1.0V
De Garrent Gain	h _{FE}	60	—		$I_C = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.30	V	$I_C = 50mA$, $I_B = 5.0mA$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$		0.95	V	$I_C = 50mA$, $I_B = 5.0mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	_	4.0	pF	$V_{CB} = 5.0V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	Cibo		8.0	pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_{C} = 0$
Small Signal Current Gain	h _{fe}	120	480	_	V_{CE} = 1.0V, I_{C} = 2.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f _T	300	_	MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz
Noise Figure	NF		5.0	dB	V_{CE} = 5.0V, I_{C} = 100μA, R_{S} = 1.0kΩ, f = 1.0kHz

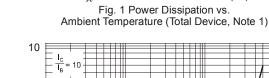
Electrical Characteristics, PNP 4126 Section @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-25	_	V	$I_{C} = -10\mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-25	_	V	I _C = -1.0mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-4.0	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	-50	nA	V _{CB} = -20V, I _E = 0V
Emitter Cutoff Current	I _{EBO}	_	-50	nA	$V_{EB} = -3.0V, I_{C} = 0V$
ON CHARACTERISTICS (Note 6)					
DC Current Gain	h _{FE}	120	360		$I_C = -2.0 \text{mA}, V_{CE} = -1.0 \text{V}$
DC Current Gain		60	_		$I_C = -50 \text{mA}, V_{CE} = -1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.40	V	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-0.95	V	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	_	4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	C _{ibo}	_	10	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$
Small Signal Current Gain	h _{fe}	120	480	_	$V_{CE} = -1.0V$, $I_{C} = -2.0mA$, $f = 1.0kHz$
Current Gain-Bandwidth Product	f _T	250	_	MHz	$V_{CE} = -20V, I_{C} = -10mA,$ f = 100MHz
Noise Figure	NF	_	4.0	dB	V_{CE} = -5.0V, I_{C} = -100μA, R_{S} = 1.0kΩ, f = 1.0kHz

Notes: 6. Short duration pulse test used to minimize self-heating effect.







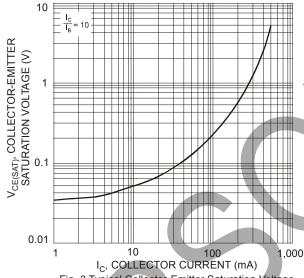


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current (PNP-4126)

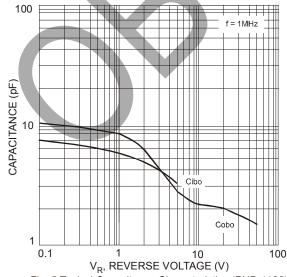
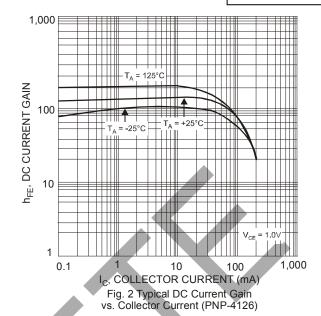


Fig. 5 Typical Capacitance Characteristics (PNP-4126)



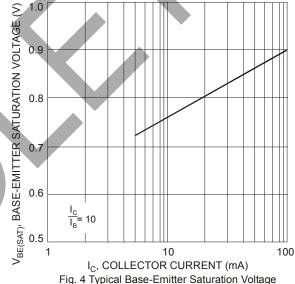
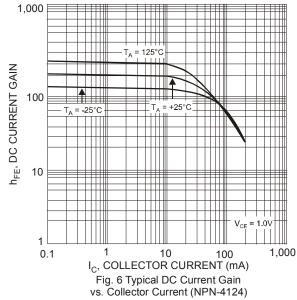
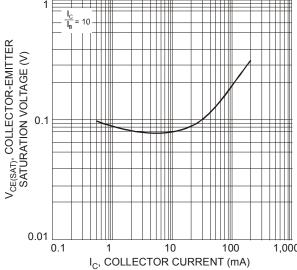
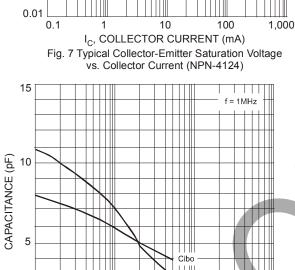


Fig. 4 Typical Base-Emitter Saturation Voltage vs. Collector Current (PNP-4126)









V_R, REVERSE VOLTAGE (V) Fig. 9 Typical Capacitance Characteristics (NPN-4124)

$V_{\text{BE(SAT)}}$, BASE-EMITTER SATURATION VOLTAGE (V) 0.1 1,000 10 I_C, COLLECTOR CURRENT (mA) Fig. 8 Typical Base-Emitter Saturation Voltage

vs. Collector Current (NPN-4124)

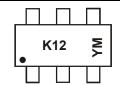
Ordering Information (Note 7)

Part Number	Case	Packaging
MMDT4146-7-F	SOT-363	3000/Tape & Reel

7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

Marking Information

0.1



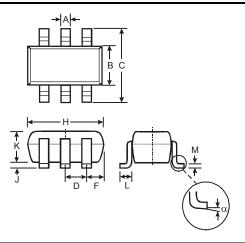
K12 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: N = 2002) M = Month (ex: 9 = September)

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	J	K	Г	М	N	Р	R	S	Т	С	V	W	Χ	Υ	Z	Α	В	С
Month	Jan		Feb	Mai	·	Apr	May	,	Jun	Jul		Aug	Sep		Oct	Nov	,	Dec
Code	1		2	3		4	5		6	7		8	9		0	N		D

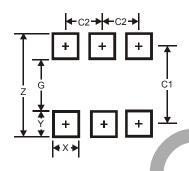


Package Outline Dimensions



	SOT-363							
Dim	Min	Max						
Α	0.10	0.30						
В	1.15	1.35						
С	2.00	2.20						
D	0.65 Typ							
F	0.40	0.45						
Н	1.80	2.20						
J	0	0.10						
K	0.90	1.00						
L	0.25	0.40						
М	0.10	0.22						
α	0°	8°						
All Di	All Dimensions in mm							

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65



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